# FAIRCHILD

SEMICONDUCTOR

## **KSA643**

# Low Frequency Power Amplifier Collector Power Dissipation: P<sub>C</sub> =500mW

- Complement to KSD261
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



# **PNP Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>CBO</sub>	Collector-Base Voltage	-40	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-20	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
I <sub>C</sub>	Collector Current (DC)	-500	mA	
I <sub>CP</sub>	* Collector Current (pulse)	-700	mA	
P <sub>C</sub>	Collector Power Dissipation	500	mW	
TJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C	

\* PW≤10ms, Duty cycle≤50%

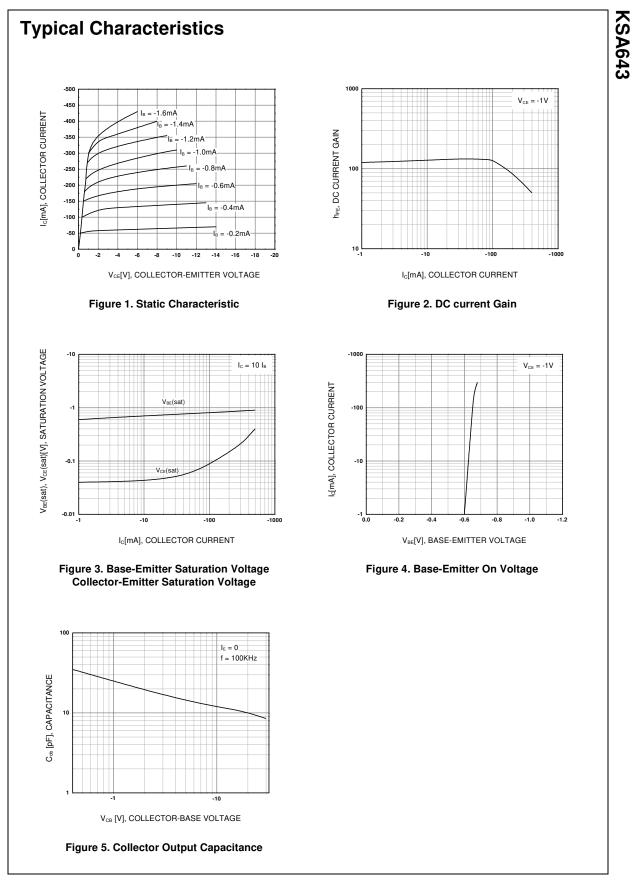
### Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -100μA, I <sub>E</sub> =0	-40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> =0	-20			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -10μΑ, I <sub>C</sub> =0	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -25V, I <sub>E</sub> =0			-200	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = -3V, I <sub>C</sub> =0			-200	nA
h <sub>FE</sub>	* DC Current Gain	V <sub>CE</sub> = -1V, I <sub>C</sub> = -100mA	40		400	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA		-0.3	- 0.4	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA		-1.0	-1.3	V

\* Pulse Test: PW≤350µs, Duty cycle≤2%

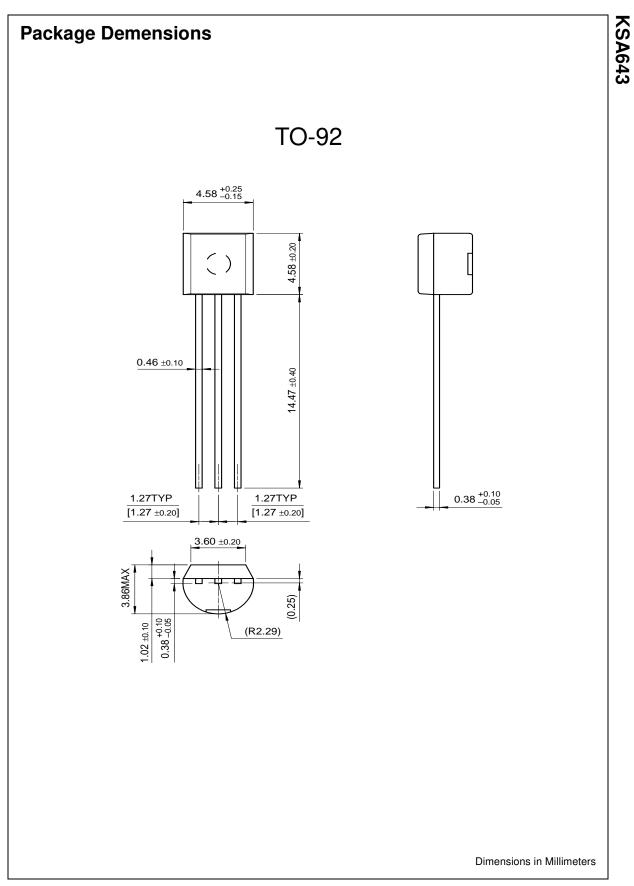
## h<sub>FE</sub> Classification

Classification	R	0	Y	G
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400



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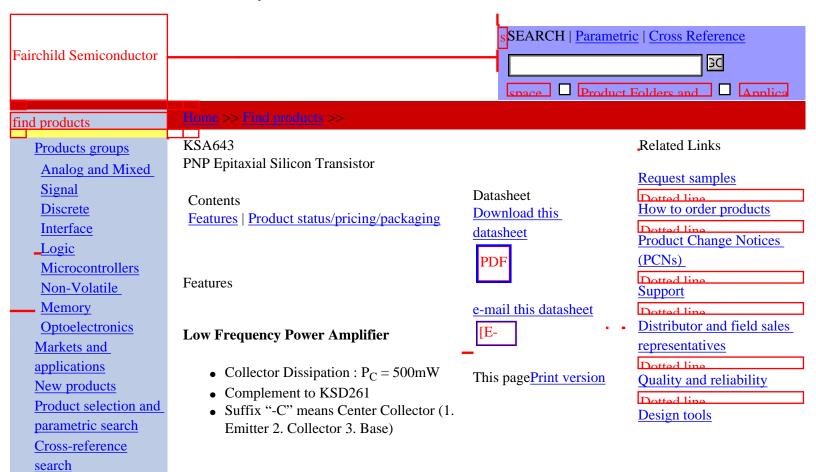
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Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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#### Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSA643CYBU	Full Production	\$0.058	<u>TO-92</u>	3	BULK
KSA643YBU	Full Production	\$0.058	<u>TO-92</u>	3	BULK
KSA643CYTA	Full Production	\$0.058	<u>TO-92</u>	3	TAPE REEL
KSA643GBU	Full Production	\$0.058	<u>TO-92</u>	3	BULK
KSA643OTA	Full Production	\$0.058	<u>TO-92</u>	3	TAPE REEL
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